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Sub	Substitute for form 1449A/PTO		Complete If Known			
				Application Number	10/087,744	
11	INFORMATION DISCLOSURE			Filing Date	March 5, 2002	
S	STATEMENT BY APPLICANT		First Named Inventor	Glen Hush		
				Art Unit	2818	
(use as many sheets as necessary)				Examiner Name	T. Le	
Sheet 1 of 4				Attorney Docket Number	M4065.0485/P485	

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Examiner Initials*	Cite No.1	Document Number  Number-Kind Code <sup>2</sup> (# known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Unes, Where Relevant Passages or Relevant Figures Appear
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		_		Application Number	10/087,744
11	<b>NFORMATIO</b>	N DI	SCLOSURE	Filing Date	March 5, 2002
S	STATEMENT BY APPLICANT			First Named Inventor	Glen Hush
				Art Unit	2818
1	(use as many sheets as necessary)			Examiner Name	T. Le
Sheet	2	of	4	Attorney Docket Number	M4065.0485/P485

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	(use as man	y sheets as ne	cessary)	Examiner Name	T. Le	
Sheet	3	of	4	Attorney Docket Number	M4065.0485/P485	

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Examiner	Cite	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant	П
Initials*	No.1	Country Code <sup>3</sup> -Number <sup>4</sup> -Kind Code <sup>5</sup> (If known)	MM-DD-YYYY	Applicant of Cited Document	Passages or Relevant Figures Appear	
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Examiner	Date	12 / A :-
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Signature CCC 9 CC	Considered	1/-2

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant

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<sup>&</sup>lt;sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See attached Kinds Codes of USPTO Patent Documents at <a href="https://www.uspto.gov">www.uspto.gov</a> or MPEP 901.04. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the Indication of the year of the reign of the Emperor must precede the application number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.

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1				Application Number	10/087,744		
11	<b>NFORMATIC</b>	N DIS	CLOSURE	Filing Date	March 5, 2002		
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				Group Art Unit	2818		
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Sheet	4	of	4	Attorney Docket Number	M4065.0485/P485		

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